

Hall Effect Sensor IC with Complementary Output Drivers

Features:

- Operate from 2.8V to 18V supply voltage.
- On-chip Hall sensor.
- Internal bandgap regulator allows temperature compensated operations and a wide operating voltage range.
- High output sinking capability up to 400mA for driving large load.
- Lower current change rate reduces the peak output voltages during switching.
- Available in rugged low profile SOT-25, SIP-4L packages.
- Built-in **FG** output.
- Built-in protection diode for reverse power supply fault.

General Description:

WSH41F is designed to integrate Hall sensor with complementary output drivers and frequency generator together on the same chip, it is suitable for speed measurement, revolution counting, positioning. It includes a temperature compensated voltage regulator, a differential amplifier, a Hysteresis controller, two open-collector output drivers capable of sinking 400mA current load and an open-collector frequency generator capable of sinking 10mA current load. An on-chip protection diode is implemented to prevent reverse power fault.

The temperature-dependent bias increases the supply voltage of the hall plates and adjusts the switching points to the decreasing induction of magnets at higher temperatures. Subsequently, the open collector output switches to the appropriate state. WSH41F are rated for operation over temperature range from –20° C to 125°C and voltage ranges from 2.8V to 18V.

In SOT-25 package, the built-in FG function can save fan system a lot of cost. It is a very economical solution when fan system need FG signal.



Pin Descriptions: SOT-25

Name	P/I/O	Pin#	Description
OUT1	О	1	Output Pin 1
Vss	P	2	Ground
OUT2	О	3	Output Pin 2
FG	О	4	Frequency Generator
VDD	P	5	Positive Power Supply

Pin Descriptions: SIP-4L

Name	P/I/O	Pin#	Description
Vcc	P	1	Positive Power Supply
OUT1	О	2	Output Pin #1
OUT2	0	3	Output Pin #2
Vss	P	4	Ground

Absolute Maximum Rating (at Ta=25° C)

Supply Voltage		Vcc		18V	
Output / FG breakdown Voltage		Vou	t/Vfg	26V	
Magnetic flux density		В		Unlimited	
Reverse Protection Voltage		Vr		20V	
Output Current	continuous	Ic		300mA	
	Hold current	Ih		400mA	
	Peak current	Ip		800mA	
FG ON Current (continuous)		If		20mA	
Operating Temperature Range		Ta		$(-20^{\circ}\text{C to } +125^{\circ}\text{C})$	
Storage Temperature Range		Ts		$(-65^{\circ}\text{C to } +150^{\circ}\text{C})$	
Package Power Dissipation		Pd		350mw for SOT-25	
				500mw for SIP-4L	

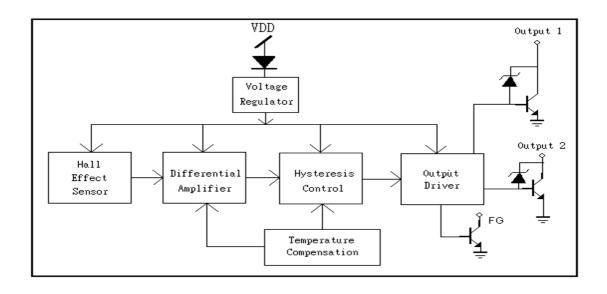


Electrical Characteristics:

$(1=\pm25)$ C. $VCC=2.8V$ TO $18V$	$\Gamma = +25^{\circ}C$, $Vcc = 2.8V$	to 18V)
------------------------------------	--	---------

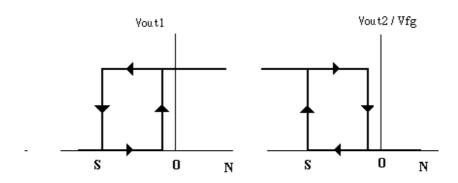
Characteristic	Symbol	Test Conditions	Min	Тур	Max	Units
Supply Voltage	Vcc		2.8	_	18	V
Output Saturation	Vout(sat)	Vcc=18V, Ic=200mA		0.2	0.4	V
Voltage		B > Bop				
FG Saturation	Vfg(sat)	Vcc=18V, If=10mA		0.15	0.4	V
Voltage		B > Bop				
Output Leakage	Ileakage	Vcc=18V, B < Brp		< 0.1	10	uA
Current						
Supply Current	Isupply	Vcc=18V, Output &		13	25	mA
		FG Open				
Output / FG Rising	Tr	Vcc=12V, RL=820Ω		3.0	10	us
Time		CL=20Pf				
Output / FG Falling	Tf	Vcc=12V, RL=820Ω		0.3	1.5	us
Time		CL=20Pf				
Output / FG Time	∆t	Vcc=12V, RL=820Ω		0.3	3	us
Differential		CL=20Pf				

Function Block:





WSH41F Complementary Output1 vs. Output2/Vfg



Magnetic Flux Density in Gauss

Magnetic Characteristics:

Characteristics	Symbol	Quantity	Min	Ta= -20°C to +90°C Typ.	Max	Unit
Operate Point	Вор	None latch			150	Gauss
Release Point	Brp	None latch	10			Gauss

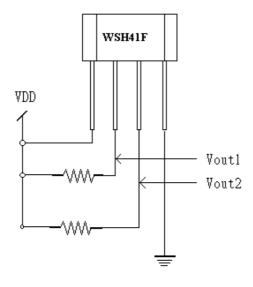
Ordering Information:

SIP- 4L: WSH41F-XPA5	Elec. Grade
SOT-25: WSH41F-XPB5	None latch: 150 Gauss

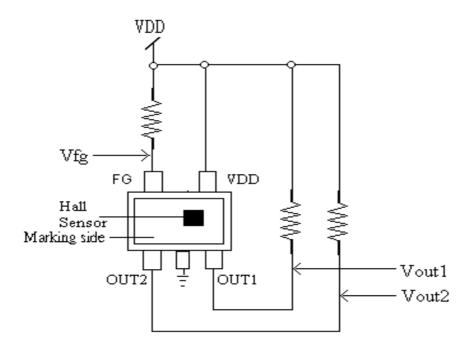


Test Circuit:

SIP-4L



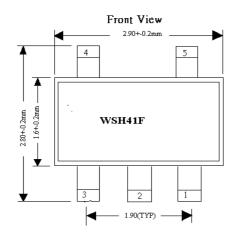
SOT-25

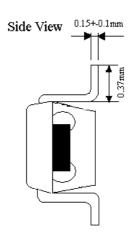


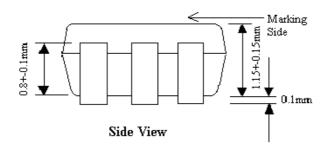


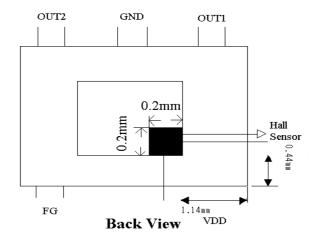
Package Information:

SOT-25











SIP-4L

Package Dimension

Hall Sensor Location

